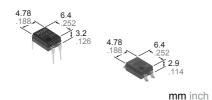
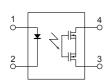


Panasonic ideas for life

General use and economy type.
DIP (1 Form B) 4-pin type.
Reinforced insulation 5,000V type.

GU-E PhotoMOS (AQY41OEH)





FEATURES

1. 60V type couples high capacity (0.55A) with low on-resistance (1 Ω)

Item	GU-E type		
Part No.	AQY410EH	AQY412EH	
Load voltage	350V	60V	
Continuous load current	0.13A	0.55A	
ON resistance (typ.)	18Ω	1Ω	

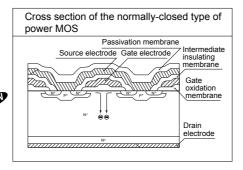
2. This is the low-cost version PhotoMOS 1 Form B output type relay.

The attainment of economical pricing will broaden its market even further.

3. Normally closed type (1 Form B) is low on-resistance.

(All AQO4 PhotoMOS are Form B types. And also the Form A types have a low on-resistance.)

This has been realized thanks to the built-in MOSFET processed by our proprietary method, DSD (Double-diffused and Selective Doping) method. Cross section of the normally-closed type of power MOS



4. Reinforced insulation 5,000 V type More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

5. Compact 4-pin DIP size

The device comes in a compact (W)6.4×(L)4.78×(H)3.2mm (W).252×(L).188×(H).126inch, 4-pin DIP size

- **6. Controls low-level analog signals** PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 7. High sensitivity, low ON resistance Can control a maximum 0.13 A load current with a 5 mA input current. Low ON resistance of 18Ω (AQY410EH). Stable operation because there are no metallic contact parts.
- 6. Low-level off-state leakage current

TYPICAL APPLICATIONS

- · Power supply
- Measuring equipment
- Security equipment
- Modem
- Telephone equipment
- · Electricity, plant equipment
- Sensors

TYPES

Type isolation voltage		-			Pa	Packing quantity					
				Through hole terminal	Sunace-mount terminal						
		ge Load Load	Lood	lube packing style		Tape and reel packing style			Tape and		
			current			Picked from the	Picked from the	Tube	reel		
			tage carroin			1/2-pin side	3/4-pin side				
	AC/DC		60 V	550 mA	AQY412EH	AQY412EHA	AQY412EHAX	AQY412EHAZ	1 tube centains 100 nes		
			351	350 / 130	130 mA	AQY410EH	AQY410EHA	AQY410EHAX	AQY410EHAZ	1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.
			400 V	120 mA	AQY414EH	AQY414EHA	AQY414EHAX	AQY414EHAZ	- Dater Contains 1,000 pcs		

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the initial letters of the product number "AQY", the SMD terminal shape indicator "A" and the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

	Item	Symbol	AQY412EH (A)	AQY410EH (A)	AQY414EH (A)	Remarks
	LED forward current	İF		50 mA		
, I	LED reverse voltage	VR		5 V		
Input	Peak forward current	IFP		1 A	f = 100 Hz, Duty factor = 0.1%	
	Power dissipation	Pin		75 mW		
Output	Load voltage (peak AC)	VL	60 V	350 V	400 V	
	Continuous load current	IL	0.55 A	0.13 A	0.12 A	
	Peak load current	Ipeak	1.5 A	0.4 A	0.3 A	100 ms (1 shot), V∟= DC
	Power dissipation	Pout	500 mW			
Total power dissipation		Рт		550 mW		
I/O isolation voltage		Viso		5,000 V AC		
Temper	ature Operating	Topr	-40°(C to +85°C -40°F to +	Non-condensing at low temperatures	
limits	Storage	Tstg	-40°C	to +100°C -40°F to -		

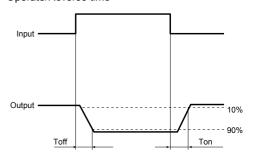
GU-E PhotoMOS (AQY41OEH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

	Item		Symbol	AQY412EH (A)	AQY410EH (A)	AQY414EH (A)	Condition
Input	LED operate (OFF) current	Typical	l- "		I∟=Max.		
		Maximum	Foff				
	LED reverse (ON) current	Minimum	l _{Fon}		l∟=Max.		
		Typical	IFON				
	LED dropout voltage	Typical	V _F	1.25 (1.14 V at I _F = 5 mA)			I _F = 50 mA
		Maximum	VF	1.5 V			
Output	On resistance	Typical	Ron	1Ω	18Ω	26Ω	$I_F = 0 \text{ mA}$ $I_L = \text{Max}$. Within 1 s on time
		Maximum		2.5Ω	25Ω	35Ω	
	Off state leakage current	Maximum	Leak	10μΑ			$I_F = 5 \text{ mA}$ $V_L = \text{Max}.$
Transfer characteristics	Operate (OFF) time*	Typical Toff	3.0 ms	1.0 ms	0.8 ms	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = \text{Max}.$	
		Maximum	Ioff	10.0 ms 3.0 ms			ms
	Reverse (ON) time*	Typical	Ton	0.2 ms	0.3 ms	0.2 ms	I _F = 5 mA → 0 mA
		Maximum	Ion		I∟ = Max.		
	I/O capacitance	Typical	Ciso	0.8 pF			f = 1MHz $V_B = 0 V$
		Maximum	Ciso	1.5 pF			
	Initial I/O isolation resistance	Minimum	Riso	1,000ΜΩ			500 V DC

Note: Recommendable LED forward current I_F = 5 to 10mA.

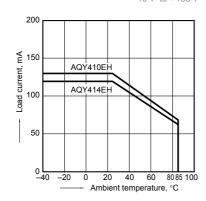
*Operate/Reverse time



REFERENCE DATA

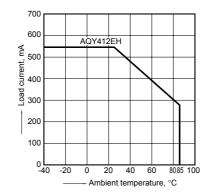
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C



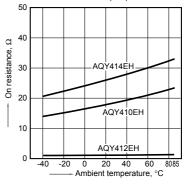
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C



2. On resistance vs. ambient temperature characteristics

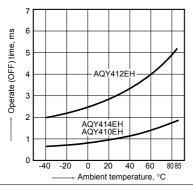
Measured portion: between terminals 3 and 4; LED current: 0 mA; Load voltage: Max.(DC); Continuous load current: Max. (DC)



GU-E PhotoMOS (AQY41OEH)

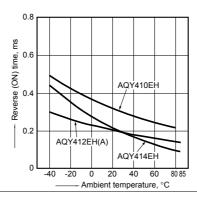
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



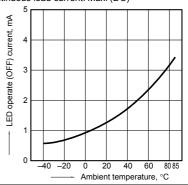
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



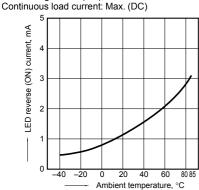
5. LED operate (OFF) current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)

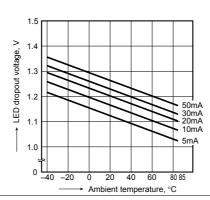


6. LED reverse (ON) current vs. ambient temperature characteristics

Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)

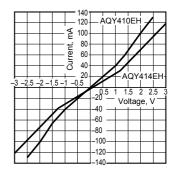


7. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



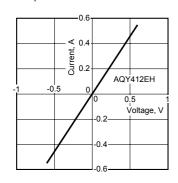
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



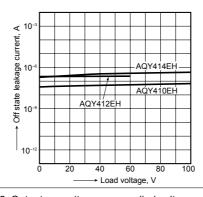
8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



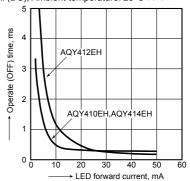
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



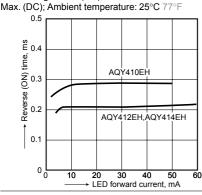
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: Max. (DC); Continuous load current:



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

